

# MC10LVEP11

## Product Preview

## Low Voltage 1:2 Differential Fanout Buffer

The MC10LVEP11 is a differential 1:2 fanout buffer. The device is pin and functionally equivalent to the EP11 device. With AC performance the same as the EP11 device, the LVEP11 is ideal for applications requiring lower voltage.

- 220ps Typical Propagation Delay
- High Bandwidth to 3 GHz Typical
- PECL mode: 2.375V to 3.8V  $V_{CC}$  with  $V_{EE} = 0V$
- ECL mode: 0V  $V_{CC}$  with  $V_{EE} = -2.375V$  to  $-3.8V$
- Internal Input Resistors: Pulldown on D, Pulldown and Pullup on  $\bar{D}$
- Q Outputs will default LOW with inputs open or at  $V_{EE}$
- ESD Protection: >4KV HBM, >200V MM
- Moisture Sensitivity Level 1, Indefinite Time Out of Drypack.  
For Additional Information, See Application Note AND8003/D
- Flammability Rating: UL-94 code V-0 @ 1/8",  
Oxygen Index 28 to 34
- Transistor Count = 73 devices

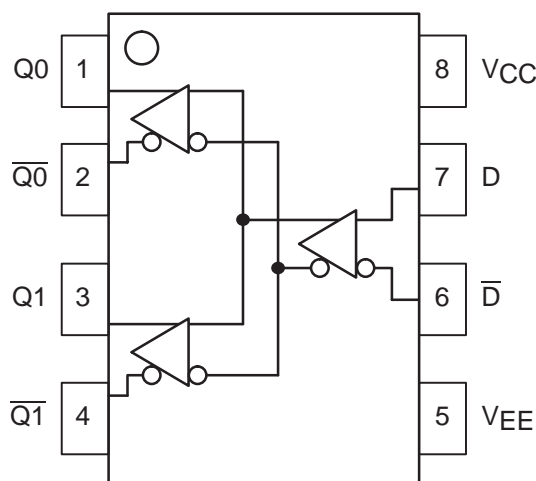


Figure 1. 8-Lead Pinout (Top View) and Logic Diagram



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### MARKING DIAGRAMS\*



SO-8  
D SUFFIX  
CASE 751



TSSOP-8  
DT SUFFIX  
CASE 948R



A = Assembly Location  
L = Wafer Lot  
Y = Year  
W = Work Week

\*For additional information, see Application Note AND8002/D

### PIN DESCRIPTION

PIN	FUNCTION
D, $\bar{D}$	ECL Data Inputs
Q0, $\bar{Q0}$ , Q1, $\bar{Q1}$	ECL Data Outputs
$V_{CC}$	Positive Supply
$V_{EE}$	Negative, 0 Supply

### ORDERING INFORMATION

Device	Package	Shipping
MC10LVEP11D	SO-8	98 Units / Rail
MC10LVEP11DR2	SO-8	2500 / Reel
MC10LVEP11DT	TSSOP-8	98 Units / Rail
MC10LVEP11DTR2	TSSOP-8	2500 / Reel

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# MC10LVEP11

## MAXIMUM RATINGS\*

Symbol	Parameter	Value	Unit
$V_{EE}$	Power Supply ( $V_{CC} = 0V$ )	-6.0 to 0	VDC
$V_{CC}$	Power Supply ( $V_{EE} = 0V$ )	6.0 to 0	VDC
$V_I$	Input Voltage ( $V_{CC} = 0V$ , $V_I$ not more negative than $V_{EE}$ )	-6.0 to 0	VDC
$V_I$	Input Voltage ( $V_{EE} = 0V$ , $V_I$ not more positive than $V_{CC}$ )	6.0 to 0	VDC
$I_{out}$	Output Current Continuous Surge	50 100	mA
$T_A$	Operating Temperature Range	-40 to +85	°C
$T_{stg}$	Storage Temperature	-65 to +150	°C
$\theta_{JA}$	Thermal Resistance (Junction-to-Ambient) (8-Pin SOIC)	Still Air 500lfpm 190 130	°C/W
$\theta_{JA}$	Thermal Resistance (Junction-to-Ambient) (8-Pin TSSOP)	Still Air 500lfpm 190 130	°C/W
$\theta_{JC}$	Thermal Resistance (Junction-to-Case)	41 to 44 $\pm$ 5%	°C/W
$T_{sol}$	Solder Temperature (<2 to 3 Seconds: 245°C desired)	265	°C

\* Maximum Ratings are those values beyond which damage to the device may occur.

## DC CHARACTERISTICS, ECL/LVECL ( $V_{CC} = 0V$ ; $V_{EE} = -3.8V$ to $-2.375V$ ) (Note 4.)

Symbol	Characteristic	-40°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
IEE	Power Supply Current (Note 1.)	20	29	37	20	30	39	22	31	40	mA
$V_{OH}$	Output HIGH Voltage (Note 2.)	-1135	-1060	-885	-1070	-945	-820	-1010	-885	-760	mV
$V_{OL}$	Output LOW Voltage (Note 2.)	-1935	-1810	-1685	-1870	-1745	-1620	-1810	-1685	-1560	mV
$V_{IH}$	Input HIGH Voltage Single Ended	-1210		-885	-1145		-820	-1085		-760	mV
$V_{IL}$	Input LOW Voltage Single Ended	-1935		-1610	-1870		-1545	-1810		-1485	mV
$V_{IHCMR}$	Input HIGH Voltage Common Mode Range (Note 3.)	$V_{EE}+1.2$		0.0	$V_{EE}+1.2$		0.0	$V_{EE}+1.2$		0.0	V
$I_{IH}$	Input HIGH Current			150			150			150	$\mu A$
$I_{IL}$	Input LOW Current	$\frac{D}{\bar{D}}$	0.5 -150		0.5 -150			0.5 -150			$\mu A$

NOTE: 10EP circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500lfpm is maintained.

1.  $V_{CC} = 0V$ ,  $V_{EE} = V_{EEmin}$  to  $V_{EEmax}$ , all other pins floating.
2. All loading with 50 ohms to  $V_{CC}-2.0$  volts.
3.  $V_{IHCMR}$  min varies 1:1 with  $V_{EE}$ , max varies 1:1 with  $V_{CC}$ .
4. Input and output parameters vary 1:1 with  $V_{CC}$ .

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## DC CHARACTERISTICS, LVPECL ( $V_{CC} = 3.3V \pm 0.3V$ , $V_{EE} = 0V$ ) (Note 8.)

Symbol	Characteristic	-40°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
IEE	Power Supply Current (Note 5.)	20	29	37	20	30	39	22	31	40	mA
VOH	Output HIGH Voltage (Note 6.)	2165	2240	2415	2230	2355	2480	2290	2415	2540	mV
VOL	Output LOW Voltage (Note 6.)	1365	1490	1615	1430	1555	1680	1490	1615	1740	mV
VIH	Input HIGH Voltage Single Ended	2090		2415	2155		2480	2215		2540	mV
VIL	Input LOW Voltage Single Ended	1365		1690	1430		1755	1490		1815	mV
VIHCMR	Input HIGH Voltage Common Mode Range (Note 7.)	1.2		3.3	1.2		3.3	1.2		3.3	V
I <sub>IH</sub>	Input HIGH Current			150			150			150	μA
I <sub>IL</sub>	Input LOW Current $\frac{D}{\bar{D}}$	0.5 -150			0.5 -150			0.5 -150			μA

NOTE: 10EP circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500lfpm is maintained.

5.  $V_{CC} = 3.3V$ ,  $V_{EE} = 0V$ , all other pins floating.

6. All loading with 50 ohms to  $V_{CC}$ -2.0 volts.

7.  $V_{IHCMR}$  min varies 1:1 with  $V_{EE}$ , max varies 1:1 with  $V_{CC}$ .

8. Input and output parameters vary 1:1 with  $V_{CC}$ .

## DC CHARACTERISTICS, PECL ( $V_{CC} = 2.5V \pm 0.125V$ , $V_{EE} = 0V$ ) (Note 12.)

Symbol	Characteristic	-40°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
IEE	Power Supply Current (Note 9.)	20	29	37	20	30	39	22	31	40	mA
VOH	Output HIGH Voltage (Note 10.)	1365	1440	1615	1430	1555	1680	1490	1615	1740	mV
VOL	Output LOW Voltage (Note 10.)	565	690	815	630	755	880	690	815	940	mV
VIH	Input HIGH Voltage Single Ended	1290		1615	1355		1680	1415		1740	mV
VIL	Input LOW Voltage Single Ended	565		890	630		955	690		1015	mV
VIHCMR	Input HIGH Voltage Common Mode Range (Note 11.)	1.2		2.5	1.2		2.5	1.2		2.5	V
I <sub>IH</sub>	Input HIGH Current			150			150			150	μA
I <sub>IL</sub>	Input LOW Current $\frac{D}{\bar{D}}$	0.5 -150			0.5 -150			0.5 -150			μA

NOTE: 10EP circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500lfpm is maintained.

9.  $V_{CC} = 2.5V$ ,  $V_{EE} = 0V$ , all other pins floating.

10. All loading with 50 ohms to  $V_{CC}$ -2.0 volts.

11.  $V_{IHCMR}$  min varies 1:1 with  $V_{EE}$ , max varies 1:1 with  $V_{CC}$ .

12. Input and output parameters vary 1:1 with  $V_{CC}$ .

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**AC CHARACTERISTICS** ( $V_{CC} = 0V$ ;  $V_{EE} = -2.375V$  to  $-3.8V$ ) or ( $V_{CC} = 2.375V$  to  $3.8V$ ;  $V_{EE} = 0V$ )

Symbol	Characteristic	-40°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
$f_{max}$	Maximum Toggle Frequency (Note 13.)		3.0			3.0			3.0		GHz
$t_{PLH}$ , $t_{PHL}$	Propagation Delay (Diff.) CLK→Q, $\bar{Q}$	140	200	270	160	220	300	180	240	320	ps
$t_{SKEW}$	Device Skew Part-to-Part (Note 14.) Q, $\bar{Q}$		TBD TBD			TBD TBD			TBD TBD		ps
$t_{JITTER}$	Cycle-to-Cycle Jitter		TBD			TBD			TBD		ps
$V_{PP}$	Input Voltage Swing (Diff.)	150	800	1200	150	800	1200	150	800	1200	mV
$t_r$ $t_f$	Output Rise/Fall Times (20% – 80%) Q, $\bar{Q}$	50	110	180	60	120	200	70	140	220	ps

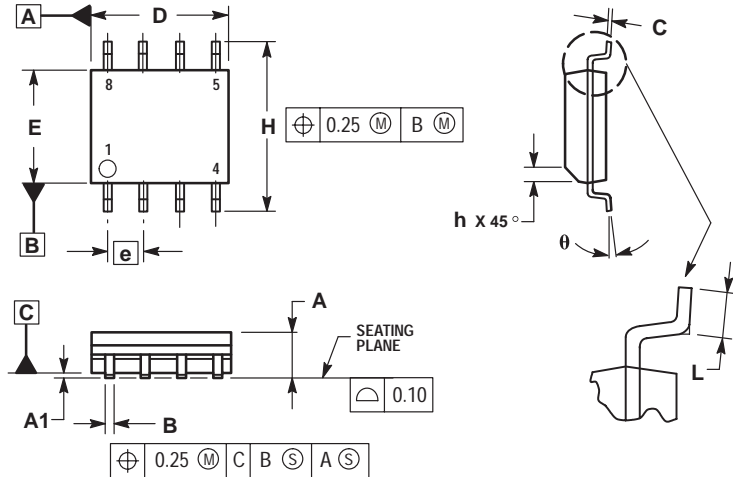
13.  $F_{max}$  guaranteed for functionality only.  $V_{OL}$  and  $V_{OH}$  levels are guaranteed at DC only.

14. Skew is measured between outputs under identical transitions.

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## PACKAGE DIMENSIONS

**SO-8**  
**D SUFFIX**  
 PLASTIC SOIC PACKAGE  
 CASE 751-06  
 ISSUE T



### NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. DIMENSIONS ARE IN MILLIMETER.
3. DIMENSION D AND E DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS	
	MIN	MAX
A	1.35	1.75
A1	0.10	0.25
B	0.35	0.49
C	0.19	0.25
D	4.80	5.00
E	3.80	4.00
e	1.27 BSC	
H	5.80	6.20
h	0.25	0.50
L	0.40	1.25
θ	0°	7°



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